HALOGEN

FREE



Vishay General Semiconductor

Dual TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.32 \text{ V}$ at $I_F = 5.0 \text{ A}$

D²PAK (TO-263AB)



LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | | | |
|---|-------------------------------|--|--|--|--|
| I _{F(AV)} | 2 x 15 A | | | | |
| V _{RRM} | 60 V | | | | |
| I _{FSM} | 200 A | | | | |
| V _F at I _F = 15 A | 0.45 V | | | | |
| T _J max. | 150 °C | | | | |
| Package | D ² PAK (TO-263AB) | | | | |
| Circuit configuration | Common cathode | | | | |

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C



TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

MECHANICAL DATA

Case: D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 and M3 suffix meet JESD 201 class 2 whisker test

Polarity: as marked

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | | |
|--|------------|-----------------------------------|-------------|------|--|--|
| PARAMETER | | SYMBOL | VBT30L60C | UNIT | | |
| Maximum repetitive peak reverse voltage | | V _{RRM} | 60 | V | | |
| Maximum average forward rectified current (fig. 1) | per device | | 30 | Δ. | | |
| | per diode | I _{F(AV)} | 15 | A | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | | I _{FSM} | 200 | А | | |
| Voltage rate of change (rated V _R) | | dV/dt | 10 000 | V/µs | | |
| Operating junction and storage temperature range | | T _J , T _{STG} | -40 to +150 | °C | | |

| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|---|------------------------|--|-------------------------------|------|------|--------|--|
| PARAMETER | TEST CO | NDITIONS | SYMBOL | TYP. | MIN. | UNIT | |
| Instantaneous forward voltage per diode | I _F = 5.0 A | T _A = 25 °C | V _F ⁽¹⁾ | 0.43 | - | V | |
| | I _F = 7.5 A | | | 0.46 | - | | |
| | I _F = 15 A | | | 0.51 | 0.60 | | |
| | I _F = 5.0 A | T _A = 125 °C | | 0.32 | - | | |
| | I _F = 7.5 A | | | 0.36 | - | | |
| | I _F = 15 A | | | 0.45 | 0.57 | | |
| Reverse current per diode | V _R = 60 V | $T_A = 25 ^{\circ}\text{C}$ $T_A = 125 ^{\circ}\text{C}$ $I_R^{(2)}$ | - | 4.0 | mA | | |
| | v _R = 60 v | | IR ^(←) | 27 | 110 |] "''A | |

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms



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| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | |
|---|------------|----------------|-----------|------|--|
| PARAMETER | | SYMBOL | VBT30L60C | UNIT | |
| Typical thermal resistance | per diode | $R_{	heta JC}$ | 1.8 | °C/W | |
| | per device | | 0.8 | C/VV | |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|-----------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| TO-263AB | VBT30L60C-E3/4W | 1.39 | 4W | 50/tube | Tube | | |
| TO-263AB | VBT30L60C-E3/8W | 1.39 | 8W | 800/reel | Tape and reel | | |
| TO-263AB | VBT30L60C-M3/I | 1.39 | I | 800/reel | Tape and reel | | |

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

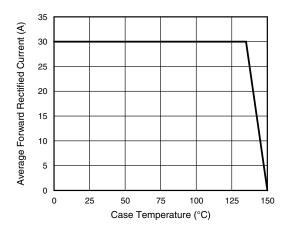


Fig. 1 - Maximum Forward Current Derating Curve

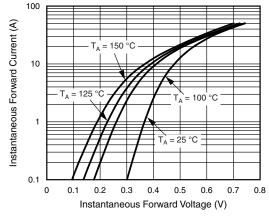


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

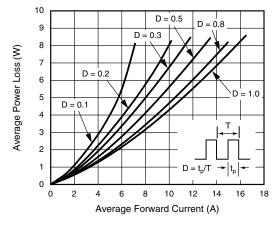


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

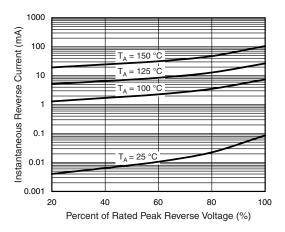


Fig. 4 - Typical Reverse Characteristics Per Diode



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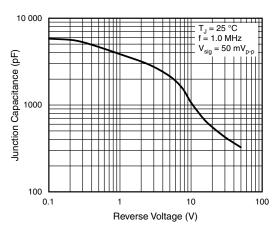


Fig. 5 - Typical Junction Capacitance Per Diode

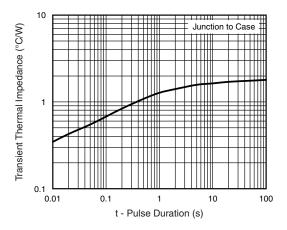
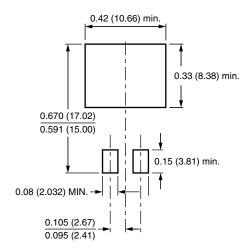


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

D²PAK (TO-263AB) 0.411 (10.45) 0.190 (4.83) 0.380 (9.65) 0.160 (4.06) 0.055 (1.40) 0.245 (6.22) 0.045 (1.14) MIN. 0.055 (1.40) 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) 0.591 (15.00) K -0 to 0.01 (0 to 0.254) <u>7</u> <u>0.11</u>0 (2.79) **▼** 0.090 (2.29) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.095 (2.41) 0.205 (5.20) 0.110 (2.79) 0.195 (4.95)

Mounting Pad Layout





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